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Instructions for Authors on the Preparation of Camera-Ready Manuscripts for Solid State Communications

- The manuscript is to be typed in single column. It will be assembled into double column format by Pergamon and reproduced photographically.
- Manuscripts should be typed single-spaced on standard size, good quality white paper, preferably
 using an electric typewriter with a black ribbon (blue does not reproduce) and a 12 point typeface.
 Examples of the pertinent parts of a camera-ready manuscript are shown on pages iii and iv at the
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DETECTION BY LOW TEMPERATURE PHOTOLUMINESCENCE OF OXYGEN RECOILS IN "THROUGH-OXIDE" ARSENIC IMPLANTED SILICON

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damage induced by arsenic implantations through SiO2 layers. The presence of an oxygen dependent damage center in only the "through-oxide" imgrowth of the SiO2 is insufficient to produce detectable oxygen-dependent luminescence after irradiation. The technique of low-temperature photoluminescence is used to study the planted samples and in none of the samples implanted into bare surfaces oxide. It is also seen that the in-diffusion of oxygen during thermal is interpreted as indicating the presence of oxygen recoils from tile

Superionic conductors which show phase changes are an intriguing group of materials to study because of the possible different origins of their transitions. For example, the following questions can be asked. Is the phase transition driven by a soft mode and does the new phase, just by chance, have the proper arrangement for fast ion conduction? Is the phase transition driven by the need for the crystal to conduct which causes a transition to a phase with useful paths for the ions to move? Is the phase change driven by a combination of these and other mechanisms, and thus some modes will soften as T approaches T ?

One way to begin to answer some of these questions is to study the lattice vibrational spectra above and below T . We report such a study in $RbAg_4I_5$ using the Raman technique and compare these results to those found in AgI, where we had previously observed very large, abrupt, reversable changes in the Raman spectra

at T_c.

RbAg₄I₅ has a first-order transition^{2, 3} at T = 121°K, where the d.c. conductivity increases by a factor 100, and a second-order phase transition at T = 208°K, where the conductivity is continuous but do/dT has a discontinuity. At room temperature RbAg4Is has a complicated cubic structure" with space group 07-P413 (or its enantiomorphic space group 06-P433). There are four formula units per cell but the material is highly disordered since the 16 Ag ions are randomly distributed over 56 sites. This space group does not have a center of inversion as a symmetry operation, yet it is not piezoelectric so infrared active phonon modes should not be Raman active (the exclusion rule) unless the disorder breaks this selection rule. On the other hand if the low temperature structures have space groups that are subgroups of 07-P413 then they will be piezoelectric and most likely have infrared modes that are also Raman active. In fact, using the electric field echo technique, we have determined that the crystal is piezoelectric below 121°K. We will return to this point in discussing the results.

The material used in this study was prepared by reacting the proper concentrations of purified AgI and RbI in a sealed silica tube. The reacted mass was then slowly lowered through a heated zone where the maximum temperature was 215°C. The resulting material contained several large crystals, with a lattice constant of

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